

**DC Input 4-Pin Phototransistor Optocoupler** 

## **Features**

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- External Creepage ≥ 7.5mm (S/SL Type)
- External Creepage ≥ 8.0mm (SLM Type)
- Operating temperature range 55 °C to 110 °C
- Regulatory Approvals
  - UL UL1577 (E364000)
  - VDE EN60747-5-5(VDE0884-5)
  - CQC GB4943.1, GB8898
  - IEC60065, IEC60950

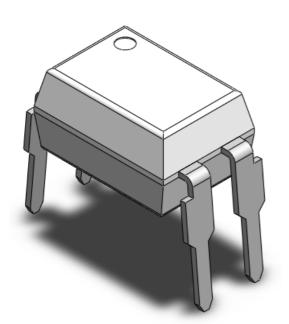
## Description

The CT817 series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead DIP package different lead forming options.

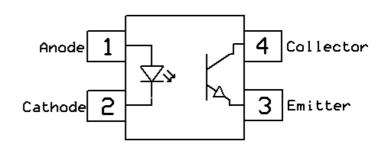
## **Applications**

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

## **Package Outline**



Schematic



Note: Different lead forming options available. See package dimension.



Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	5000	VRMS	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +110	°C	
Tstg	Storage temperature	-55 ~ +150	°C	
TSOL	Soldering temperature	260	°C	
Emitter				
lF	Forward current	60	mA	
I <sub>F(TRANS)</sub>	Peak transient current (≤1µs P.W,300pps)	1	А	
V <sub>R</sub>	Reverse voltage	6	V	
PD	Emitter power dissipation	100	mW	
Detector		·	·	
PD	Detector power dissipation	150	mW	
BVCEO	Collector-Emitter Breakdown Voltage	35	V	
BVECO	Emitter-Collector Breakdown Voltage	6	V	
lc	Collector Current	50	mA	

## Absolute Maximum Rating at 25°C



## **Electrical Characteristics** T<sub>A</sub> = 25 °C (unless otherwise specified)

#### **Emitter Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I⊧=10mA	-	1.24	1.4	V	
IR	Reverse Current	V <sub>R</sub> = 6V	-	-	5	μA	
CIN	Input Capacitance	f= 1MHz	-	10	30	pF	

#### **Detector Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
BVCEO	Collector-Emitter Breakdown	I <sub>C</sub> = 100μA	35	-	-	V	
BVECO	Emitter-Collector Breakdown	I <sub>E</sub> = 100μA	6	-	-	V	
ICEO	Collector-Emitter Dark Current	V <sub>CE</sub> = 20V, I <sub>F</sub> =0mA	-	-	100	nA	

# **Transfer Characteristics**

Symbol	Parameters		Test Conditions	Min	Тур	Max	Units	Notes
	Current Transfer Ratio CT817B CT817C	CT817	IF= 5mA, V <sub>CE</sub> = 5V	50	-	600	%	
		CT817A		80	-	160		
CTR		CT817B		130	-	260		
		CT817C		200	-	400		
		CT817D		300	-	600		
Manual	Collector-Emitter Satura	ation	L 00mA L 1mA		0.1	0.2	V	
V <sub>CE(SAT)</sub>	Voltage		I <sub>F</sub> = 20mA, I <sub>C</sub> = 1mA	-	0.1	0.2	V	
RIO	Isolation Resistance		VIO= 500VDC	5x10 <sup>10</sup>	-	-		
Сю	Isolation Capacitance		f= 1MHz	-	0.25	1	pF	

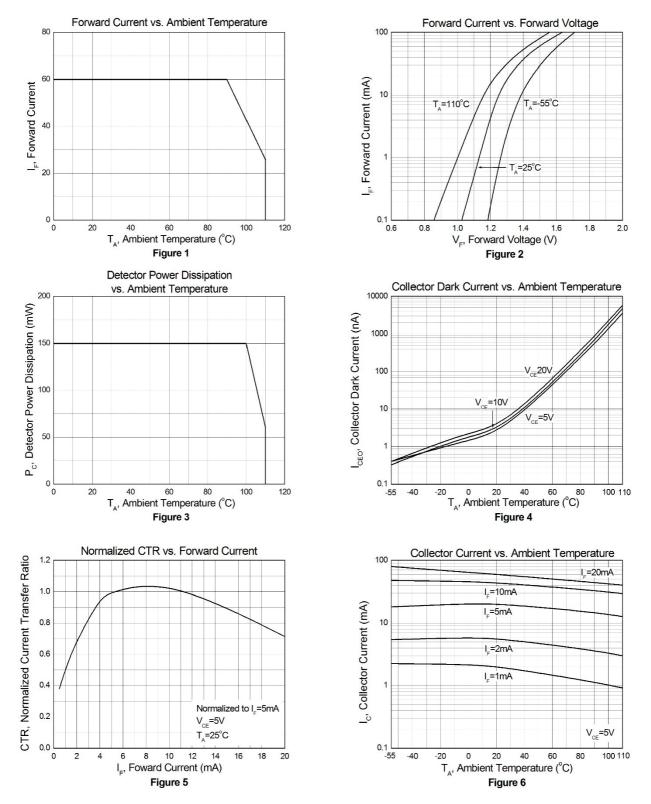
#### **Switching Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time	$I_{C}=2mA$ , $V_{CE}=2V$	-	6	18	0	
t <sub>f</sub>	Fall Time	R <sub>L</sub> = 100	-	8	18	μS	



CT817 Series DC Input 4-Pin Phototransistor Optocoupler

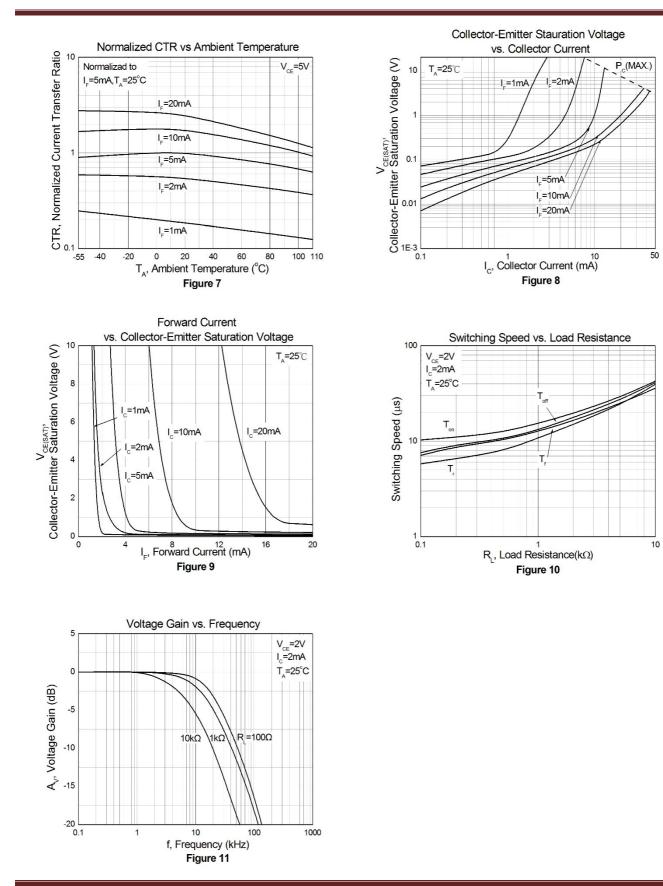
# **Typical Characteristic Curves**





# **CT817 Series**

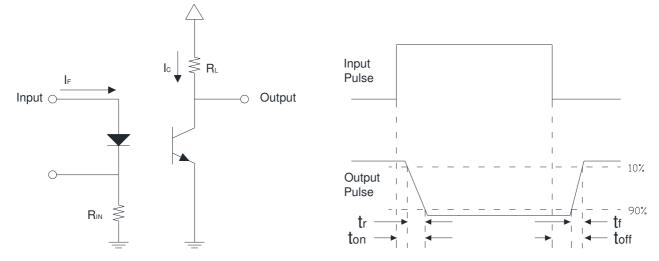






CT817 Series DC Input 4-Pin Phototransistor Optocoupler

# **Test Circuit**

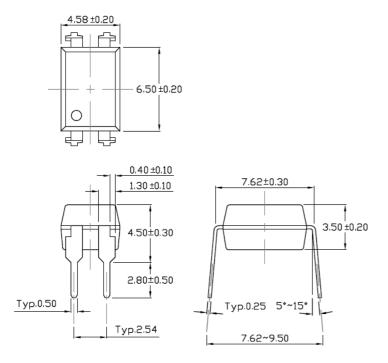




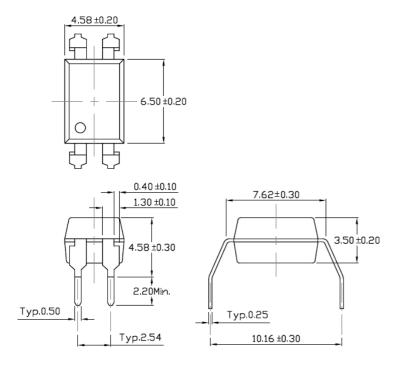


#### Package Dimension Dimensions in mm unless otherwise stated

#### Standard DIP – Through Hole

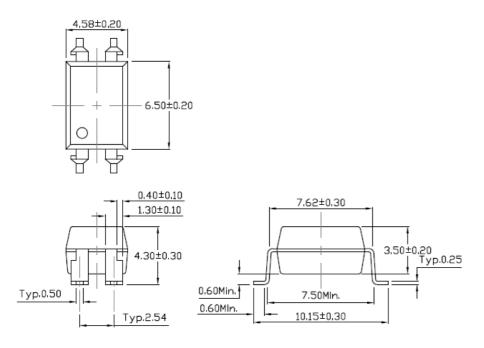


#### Gullwing (400mil) Lead Forming – Through Hole (M Type)

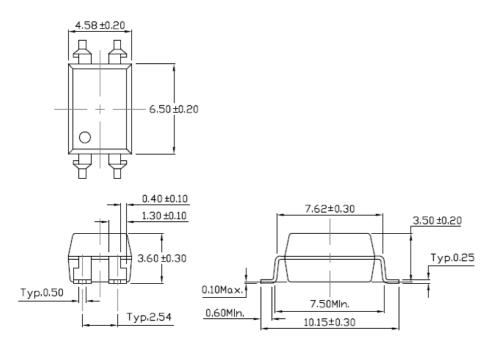




## Surface Mount Lead Forming (S Type)

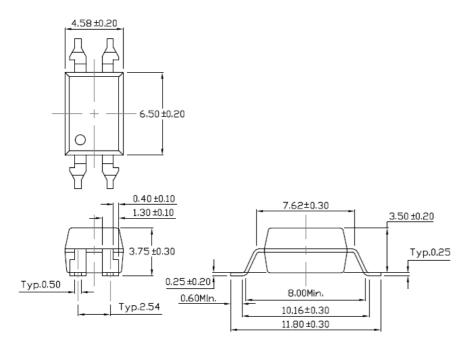


#### Surface Mount (Low Profile) Lead Forming (SL Type)





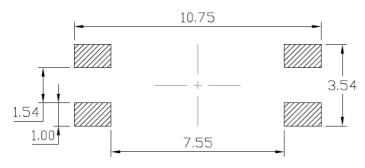
#### Surface Mount (Gullwing) Lead Forming (SLM Type)



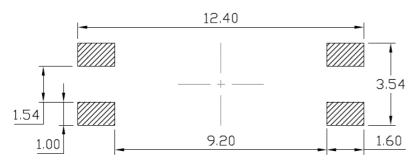


#### Recommended Solder Mask Dimensions in mm unless otherwise stated

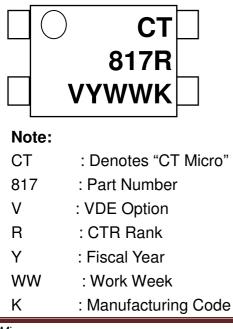
#### Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



#### Surface Mount (Gullwing) Lead Forming



# **Marking Information**





## **Ordering Information**

# CT817X(V)(Y)(Z)-HG

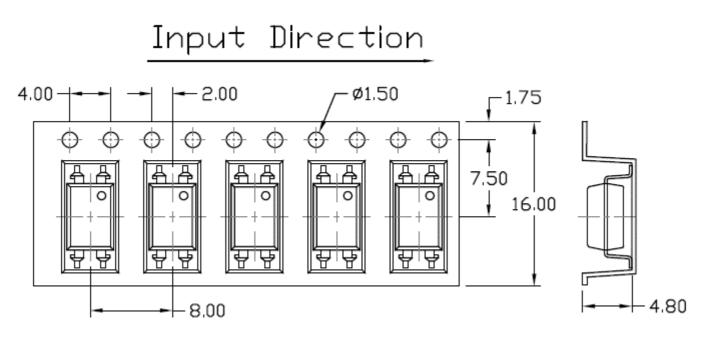
- X = Part No. (X=A, B, C, D or None)
- V = VDE Option (V or None)
- Y = Lead form option (S, SL, M, SLM or none)
- Z = Tape and reel option (T1, T2, T3, T4 or none)
- H = Lead frame option (H: Iron, None: Copper)
- G= Material option (G: Green, None: Non-green)

Option	Description	Quantity
None	Standard 4 Pin Dip	100 Units/Tube
М	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
S(T3)	Surface Mount Lead Forming – With Option 3 Taping	1000 Units/Reel
S(T4)	Surface Mount Lead Forming – With Option 4 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming- With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T3)	Surface Mount (Low Profile) Lead Forming- With Option 3 Taping	1000 Units/Reel
SL(T4)	Surface Mount (Low Profile) Lead Forming – With Option 4 Taping	1000 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming- With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel

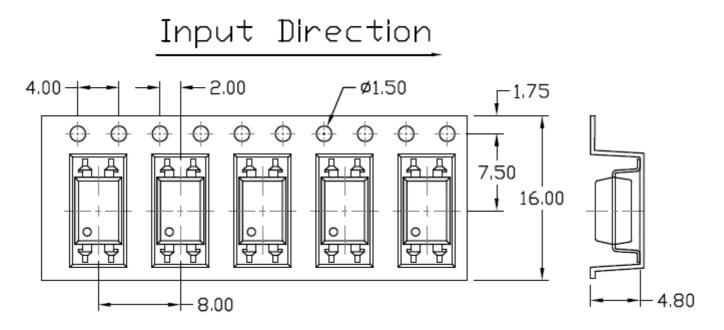




## Option S(T1) & SL(T1)



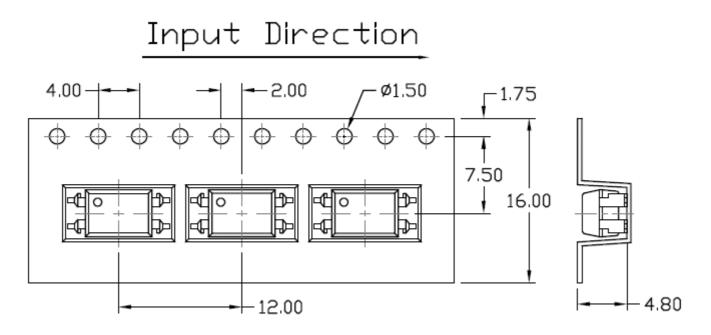
## Option S(T2) & SL(T2)



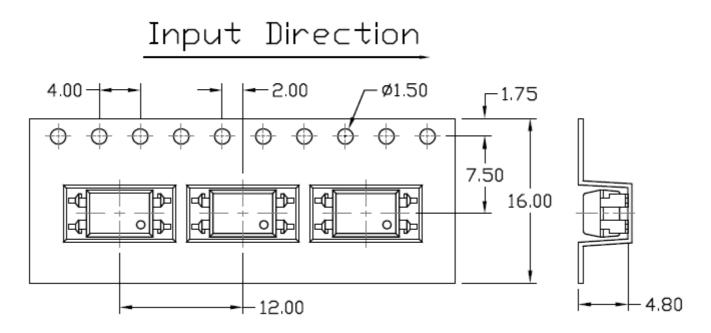


CT817 Series DC Input 4-Pin Phototransistor Optocoupler

# Option S(T3) & SL(T3)



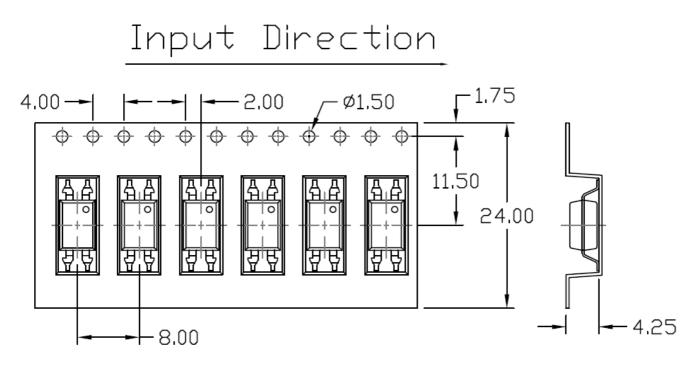
## Option S(T4) & SL(T4)



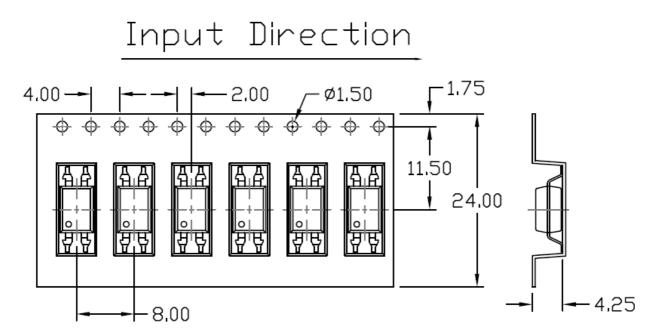


CT817 Series DC Input 4-Pin Phototransistor Optocoupler

Option SLM(T1)



**Option SLM(T2)** 

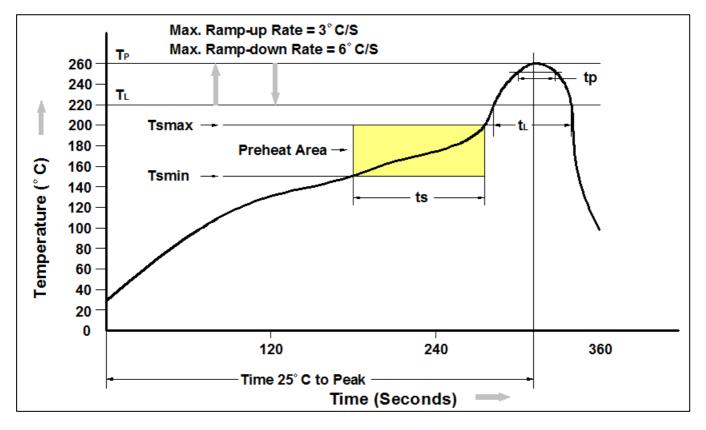




**CT817 Series** 

# **DC Input 4-Pin Phototransistor Optocoupler**

# **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile			
Temperature Min. (Tsmin)	150 <i>°</i> C			
Temperature Max. (Tsmax)	200 <i>°</i> C			
Time (ts) from (Tsmin to Tsmax)	60-120 seconds			
Ramp-up Rate ( $t_L$ to $t_P$ )	3℃/second max.			
Liquidous Temperature (TL)	217℃			
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds			
Peak Body Package Temperature	260 ℃ +0 ℃ / -5 ℃			
Time (t₀) within 5 °C of 260 °C	30 seconds			
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max			
Time 25℃ to Peak Temperature	8 minutes max.			



#### DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

DISCOLORATION MIGHT OCCUR ON THE PACKAGE SURFACE AFTER SOLDERING, REFLOW OR LONG TERM USE. THIS DOES NOT IMPACT THE PRODUCT PERFORMANCE NOR THE PRODUCT RELIABILITY.

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.